Special Issue

Nitride Semiconductor Devices and Applications

Message from the Guest Editors

This Special Issue on "Nitride Semiconductor Devices and Applications" focuses on nitride semiconductor growth and characterization, nitride semiconductor devices, and their application circuits. The main goal of Special Issue is to highlight new scientific knowledge relevant, but not limited, to:

- Nitride semiconductor epitaxy growth and characterization;
- Nitride semiconductor devices: RF/power/LED/LD, etc.;
- RF application circuits: PA, LNA, Switch, etc.;
- Power IC: DC/DC converter, inverter, driver, etc.

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Electronics is a multidisciplinary journal designed to appeal to a diverse audience of research scientists, practitioners, and developers in academia and industry. The journal is devoted to fast publication of latest technological breakthroughs, cutting-edge developments, and timely reviews of current and emerging technologies related to the broad field of electronics. Experimental and theoretical results are published as regular peer-reviewed articles or as articles within Special Issues guest-edited by leading experts in selected topics of interest.

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